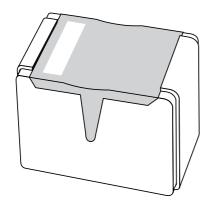
## **DISCRETE SEMICONDUCTORS**

## DATA SHEET



# **BAT254**Schottky barrier diode

Product specification Supersedes data of 1999 Apr 22 2002 May 28





## Schottky barrier diode

**BAT254** 

#### **FEATURES**

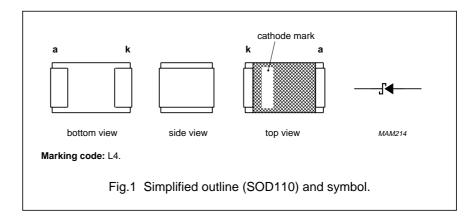
- · Low forward voltage
- · Guard ring protected
- Very small ceramic SMD package.

#### **APPLICATIONS**

- Ultra high-speed switching
- Voltage clamping
- · Protection circuits
- Blocking diodes.

#### **DESCRIPTION**

Planar Schottky barrier diode encapsulated in a SOD110 very small ceramic SMD package.



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>R</sub>	continuous reverse voltage		_	30	V
I <sub>F</sub>	continuous forward current		_	200	mA
I <sub>FRM</sub>	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	_	300	mA
I <sub>FSM</sub>	non-repetitive peak forward current	t <sub>p</sub> < 10 ms	_	600	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	125	°C
T <sub>amb</sub>	operating ambient temperature		-65	+125	°C

## Schottky barrier diode

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#### **ELECTRICAL CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V <sub>F</sub>	forward voltage	see Fig.2		
		I <sub>F</sub> = 0.1 mA	240	mV
		I <sub>F</sub> = 1 mA	320	mV
		I <sub>F</sub> = 10 mA	400	mV
		I <sub>F</sub> = 30 mA	500	mV
		I <sub>F</sub> = 100 mA	800	mV
I <sub>R</sub>	reverse current	V <sub>R</sub> = 25 V; note 1; see Fig.3	2	μΑ
t <sub>rr</sub>	reverse recovery time	when switched from $I_F$ = 10 mA to $I_R$ = 10 mA; $R_L$ = 100 $\Omega$ ; measured at $I_R$ = 1 mA; see Fig.5	5	ns
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; see Fig.4	10	pF

#### Note

1. Pulse test:  $t_p = 300 \ \mu s$ ;  $\delta = 0.02$ .

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	315	K/W

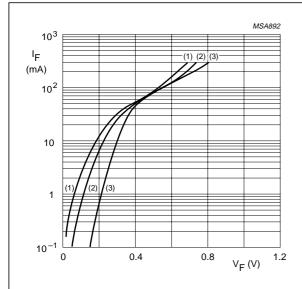
#### Note

1. Refer to SOD110 standard mounting conditions.

## Schottky barrier diode

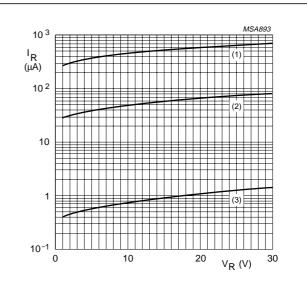
**BAT254** 

#### **GRAPHICAL DATA**



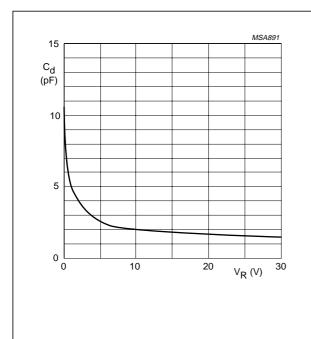
- (1)  $T_{amb} = 125 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \,^{\circ}C$ .

Fig.2 Forward current as a function of forward voltage; typical values.



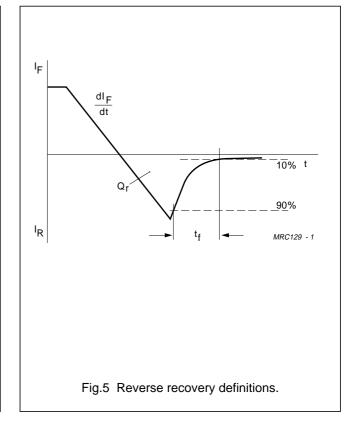
- (1)  $T_{amb} = 125 \, ^{\circ}C$ . (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \,^{\circ}C$ .

Fig.3 Reverse current as a function of reverse voltage; typical values.



f = 1 MHz;  $T_{amb} = 25 \, ^{\circ}\text{C}$ .

Fig.4 Diode capacitance as a function of reverse voltage; typical values.



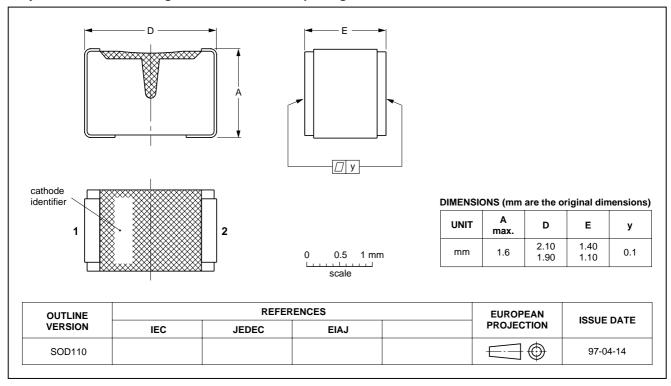
## Schottky barrier diode

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#### **PACKAGE OUTLINE**

#### Very small ceramic rectangular surface mounted package

SOD110



### Schottky barrier diode

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#### **DATA SHEET STATUS**

DATA SHEET STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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## Schottky barrier diode

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NOTES

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#### **Contact information**

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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